



# THE DATASHEET OF DHG30I600HA



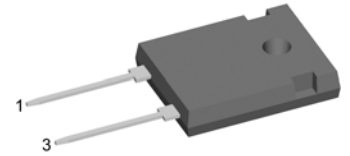
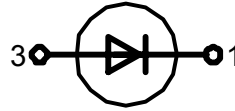
# Sonic-FRD

High Performance Fast Recovery Diode  
 Low Loss and Soft Recovery  
 Single Diode

$V_{RRM} = 600\text{ V}$   
 $I_{FAV} = 30\text{ A}$   
 $t_{rr} = 35\text{ ns}$

Part number (Marking on product)

**DHG 30 I 600HA**



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{RM}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package:

- TO-247AD
- Industry standard outline
  - Epoxy meets UL 94V-0
  - RoHS compliant

### Ratings

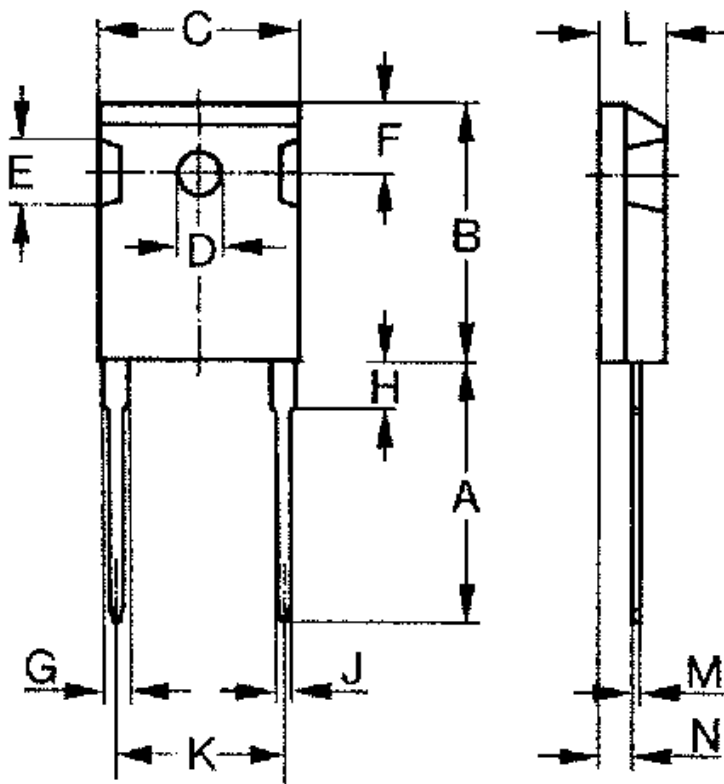
Symbol	Definition	Conditions	Ratings			Unit	
			min.	typ.	max.		
$V_{RRM}$	max. repetitive reverse voltage	$T_{VJ} = 25\text{ °C}$			600	V	
$I_R$	reverse current	$V_R = 600\text{ V}$			50	$\mu\text{A}$	
		$V_R = 600\text{ V}$			5	mA	
$V_F$	forward voltage	$I_F = 30\text{ A}$			2.36	V	
		$I_F = 60\text{ A}$				V	
		$I_F = 30\text{ A}$	$T_{VJ} = 125\text{ °C}$			2.20	V
		$I_F = 60\text{ A}$					V
$I_{FAV}$	average forward current	rectangular, $d = 0.5$			30	A	
$V_{FO}$	threshold voltage	} for power loss calculation only			1.31	V	
$r_F$	slope resistance				28.6	$\text{m}\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.70	K/W	
$T_{VJ}$	virtual junction temperature		-55		150	$^{\circ}\text{C}$	
$P_{tot}$	total power dissipation	$T_C = 25\text{ °C}$			180	W	
$I_{FSM}$	max. forward surge current	$t_p = 10\text{ ms (50 Hz), sine}$			200	A	
$I_{RM}$	max. reverse recovery current	$I_F = 30\text{ A};$		12		A	
		$-di_F/dt = 600\text{ A}/\mu\text{s}$				A	
$t_{rr}$	reverse recovery time	$V_R = 400\text{ V}$		35		ns	
						ns	
$C_J$	junction capacitance	$V_R = 300\text{ V}; f = 1\text{ MHz}$				pF	
$E_{AS}$	non-repetitive avalanche energy	$I_{AS} = \text{A}; L = 100\text{ }\mu\text{H}$			tbd	mJ	
$I_{AR}$	repetitive avalanche current	$V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$			tbd	A	

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
$I_{RMS}$	RMS current	per pin*			70	A
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W
$M_D$	mounting torque		0.8		1.2	Nm
$F_C$	mounting force with clip		20		120	N
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g

\* Irms is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.



### Outlines TO-247AD



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

-  [View DHG30I600HA on WIN SOURCE](#)
-  [IXYS Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management